# PH1214-110M

# Radar Pulsed Power Transistor 110W, 1.2-1.4 GHz, 150µs Pulse, 10% Duty

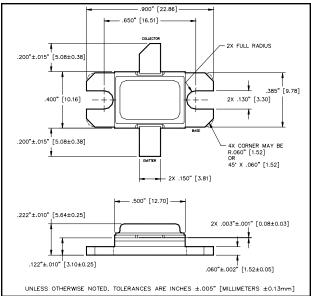
#### Features

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant



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#### **Outline Drawing**



#### Absolute Maximum Ratings at 25°C

| Parameter                 | Symbol           | Rating      | Units |
|---------------------------|------------------|-------------|-------|
| Collector-Emitter Voltage | V <sub>CES</sub> | 70          | V     |
| Emitter-Base Voltage      | V <sub>EBO</sub> | 3.0         | V     |
| Collector Current (Peak)  | Ι <sub>C</sub>   | 10.5        | А     |
| Power Dissipation @ +25°C | P <sub>TOT</sub> | 350         | W     |
| Storage Temperature       | T <sub>STG</sub> | -65 to +200 | °C    |
| Junction Temperature      | TJ               | 200         | °C    |

#### Electrical Specifications: T<sub>c</sub> = 25 ± 5°C (Room Ambient )

| Parameter                           | Test Conditions        | Frequency             | Symbol              | Min | Мах   | Units |
|-------------------------------------|------------------------|-----------------------|---------------------|-----|-------|-------|
| Collector-Emitter Breakdown Voltage | I <sub>C</sub> = 100mA |                       | BV <sub>CES</sub>   | 70  | -     | V     |
| Collector-Emitter Leakage Current   | V <sub>CE</sub> = 40V  |                       | I <sub>CES</sub>    | -   | 5.5   | mA    |
| Thermal Resistance                  | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | R <sub>TH(JC)</sub> | -   | 0.5   | °C/W  |
| Output Power                        | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | P <sub>OUT</sub>    | 110 | -     | W     |
| Power Gain                          | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | G <sub>P</sub>      | 7.4 | -     | dB    |
| Collector Efficiency                | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | η <sub>c</sub>      | 50  | -     | %     |
| Input Return Loss                   | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | RL                  | -   | -9    | dB    |
| Load Mismatch Tolerance             | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | VSWR-T              | -   | 3:1   | -     |
| Load Mismatch Stability             | Vcc = 40V, Pin = 20W   | F = 1.2, 1.3, 1.4 GHz | VSWR-S              | -   | 1.5:1 | -     |

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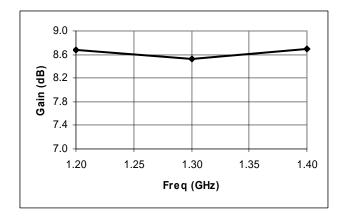
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|--|
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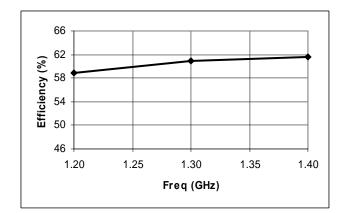
#### **Typical RF Performance**

| Freq.<br>(GHz) | Pin<br>(W) | Pout<br>(W) | Gain<br>(dB) | lc<br>(A) | Eff<br>(%) | RL<br>(dB) | VSWR-S<br>(1.5:1) | VSWR-T<br>(3:1) |
|----------------|------------|-------------|--------------|-----------|------------|------------|-------------------|-----------------|
| 1.2            | 20         | 148         | 8.68         | 6.26      | 59.0       | -10.0      | S                 | Р               |
| 1.3            | 20         | 143         | 8.53         | 5.86      | 60.8       | -11.0      | S                 | Р               |
| 1.4            | 20         | 148         | 8.69         | 6.00      | 61.7       | -25.6      | S                 | Р               |

Gain vs. Frequency



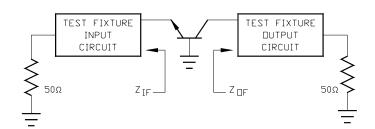
## **Collector Efficiency vs. Frequency**



#### **RF Test Fixture Impedance**

2

| F (GHz) | Z <sub>IF</sub> (Ω) | Z <sub>OF</sub> (Ω) |  |  |
|---------|---------------------|---------------------|--|--|
| 1.2     | 4.7 - j4.4          | 4.4 - j3.3          |  |  |
| 1.3     | 4.5 - j3.3          | 3.0 - j2.8          |  |  |
| 1.4     | 4.5 - j2.3          | 2.3 - j1.8          |  |  |



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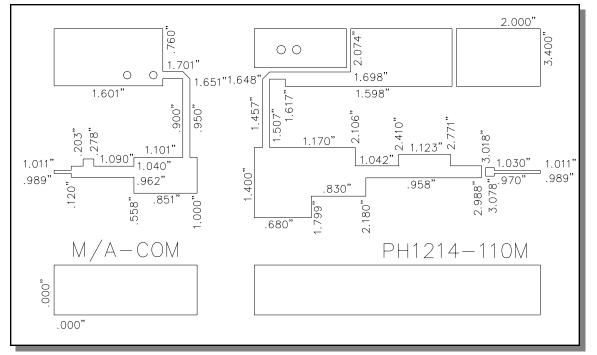
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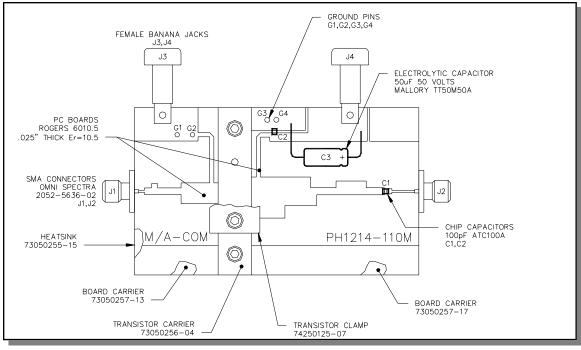
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## **Test Fixture Circuit Dimensions**



# **Test Fixture Assembly**

3



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